

High voltage LDO with connect error detection

## MM4007 Series

#### **Overview**

The MM4007 is a high voltage 300mA LDO with connection detection. The IC can be directly used to car battery by operating input voltage 36V.

The IC supplies the power for external connection equipment of car navigation (Camera, Radio, TV, etc.), and the IC can detect open or short-circuit of output load.

#### **Features**

- High voltage operation
- Open/Short circuit detection
- ON/OFF control

#### Main specifications

- Maximum rating supply voltage : -0.3V to 45V Operating voltage range : 5 to 36V Operating ambient temperature : -40℃ to 105℃ Output current : 300mA Input current (OFF) : Max. 1µA No-load input current : Typ. 400µA Output voltage range : 5V to 10V (Adj.) FB pin voltage : 2.350V±1% Line regulation
- Load regulation
- Dropout voltage
- PSRR
- Rop pin current
- Rsc pin current
- Error output
- Output capacitor
- Protection function
- Additional function

- : Max. 0.1%/V (V<sub>DD</sub>=12V to 36V)
- : Typ. 15mV (I<sub>OUT</sub>=1mA to 300mA)
- : Typ. 0.5V (V<sub>OUT</sub>(Typ.)=8V, I<sub>OUT</sub>=300mA)
- : Typ. 80dB (f=1kHz)
- : ±10% (I<sub>OUT</sub>=5mA, Vrop=1.47V)
- : ±10% (I<sub>OUT</sub>=100mA, Vrsc=1.47V)
- : Open circuit Error, Short circuit Error
- : 4.7uF (Ceramic capacitor)
- : Over current protection, Thermal shutdown, Over voltage protection
- : ON/OFF control, Connection error detection (open/short flag output) Error detect delay time

#### **Packages**

SSON-10B

#### Application

- In-vehicle infotainment device
- Power supply for antenna



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### 機種名

## M M 4 0 0 7 A 0 0 R R E

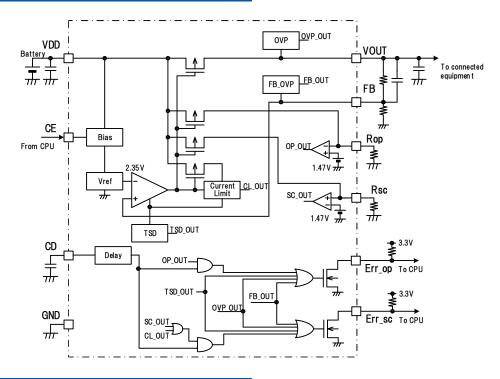
(A)

Series name

(B) (C) (D) (E)

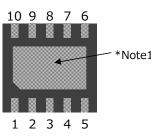
| (A) | Function Type            | А  | -                          |
|-----|--------------------------|----|----------------------------|
| (B) | Output voltage rank      | 00 | Adjustable output voltage  |
| (C) | Package                  | R  | SSON-10B                   |
| (D) | Packing specifications 1 | R  | R housing                  |
| (E) | Packing specifications 2 | Е  | Emboss tape / Halogen free |

### **Block Diagram**



#### **Pin Configuration**

SSON-10B



Top view

| Pin No. | Pin name                                       | Function  |
|---------|--|---|
| 1       | V <sub>OUT</sub>                               | Output voltage pin  |
| 2       | FB   | Output voltage feedback pin<br>Output voltage is set by adjusting the resistor between<br>VOUT, FB and GND. |
| 3       | Rop  | Open load detection resistance pin<br>Open load current is set by resistor.                                 |
| 4       | Rsc  | Short-circuit detection resistance pin<br>Short-circuit current is set by resistor.                         |
| 5       | CD   | Delay time setting pin.<br>Detection time is set by capacitor.  |
| 6       | Err_sc   | Short-circuit detection output pin<br>Resistor is connected for pull-up.                                    |
| 7       | Err_op   | Open load detection output pin.<br>Resistor is connected for pull-up.                                       |
| 8       | GND  | Ground pin  |
| 9       | CE   | Chip enable pin   |
| 10      | $V_{DD}$                                       | Power supply input pin  |
|         | 1<br>2<br>3<br>4<br>5<br>6<br>7<br>8<br>9<br>9 | 1Vout2FB3Rop4Rsc5CD6Err_sc7Err_op8GND9CE  |

\*Note1:裏タブはGNDに接続して下さい

### Absolute Maximum Ratings

| Item                       | Symbol            | Min. | Max. | Unit |
|----------------------------|-------------------|------|------|------|
| Supply voltage             | $V_{IN}$          | -0.3 | 45   | V    |
| VOUT pin voltage           | V <sub>OUT</sub>  | -0.3 | 45   | V    |
| CE pin voltage             | Vcont             | -0.3 | 45   | V    |
| Err_op, Err_sc pin voltage | Iomax             | -0.3 | 5    | V    |
| Output current             | Verr              | -    | 400  | mA   |
| Err_op, Err_sc pin current | Ierr              | -    | 20   | mA   |
| Junction Temperature       | Тј <sub>МАХ</sub> | -    | 150  | ĉ    |
| Storage temperature        | Tstg              | -55  | 150  | C    |
| Power Dissipation          | Pd                | -    | 1770 | mW   |

\*Note2:VDD≥VOUT condition. Except input and output voltage is reverse.

\*Note3:In considering product life, please examine the use in less than 80%.

\*Note4:JEDEC51-7 standard 114.3mm×76.2mm, t=1.6mm

#### Recommended Operating Conditions

| Item                          | Symbol           | Min. | Max. | Unit |
|-------------------------------|------------------|------|------|------|
| Operating Ambient temperature | Topr             | -40  | 105  | C    |
| Operating voltage             | Vop              | 5    | 36   | V    |
| Output voltage range          | V <sub>OUT</sub> | 5    | 10   | V    |
| Output current                | Іор              | 0    | 300  | mA   |

#### Electrical Characteristics

(V<sub>OUT</sub>(Typ.)=8V, V<sub>DD</sub>=12V, V<sub>CE</sub>=2.5V, Io=1mA, Ta=25℃, unless otherwise specified)

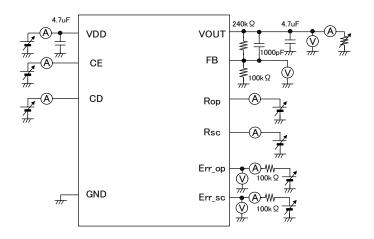
| Item                                    | Symbol   | Conditions                           | Min.  | Тур.  | Max.  | Unit  |
|---|----------|--------------------------------------|-------|-------|-------|-------|
| OFF input current                       | IDD_off  | VCE=0V, Io=0A                        | -     | -     | 1.0   | μA    |
| No-load input current                   | IDD      | Io=0A                                | -     | 400   | 800   | μA    |
| FB pin voltage                          |          | Ta=25℃                               | 2.327 | 2.350 | 2.374 | μA    |
|   | VFB      | -40℃≦Ta≦105℃ *Note5                  | 2.303 | 2.350 | 2.397 | V     |
| FB voltage temperature coefficient      | ⊿VFB/⊿Ta | -40℃≦Ta≦105℃                         | -     | 100   | -     | ppm/℃ |
| Line regulation                         | Vline    | VDD=12V to 36V                       | -     | 0.02  | 0.1   | %/V   |
| Load regulation                         | Vload    | Io=1mA to 300mA                      | -     | 15    | 60    | mV    |
| Dropout voltage                         | Vio      | VOUT(TYP.)=8V, VDD=7.8V,<br>Io=300mA | -     | 0.5   | 0.8   | V     |
| Output current limit                    | Icl      | VOUT=0V                              | 300   | 700   | 1200  | mA    |
| Power supply ripple rejection<br>*Note5 | RR       | Vripple=0.5Vp-p, f=1kHz              | -     | 80    | -     | dB    |

\*Note5:The parameter is guaranteed by design.

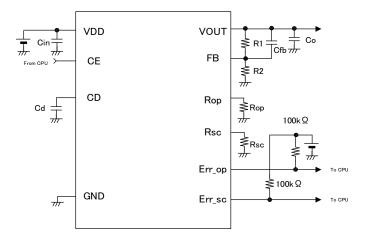
### **Electrical Characteristics**

| $(V_{OUT}(Typ.)=8V, V_{DD}=12V, V_{CE}=2.5V, Io=1mA, Ta=25$ °C, unless otherwise specified) |         |                       |      |      |      |      |  |  |
|---|---------|-----------------------|------|------|------|------|--|--|
| Item  | Symbol  | Conditions            | Min. | Тур. | Max. | Unit |  |  |
| CE input voltage high   | VCEH    |                       | 2.5  | -    | 36   | V    |  |  |
| CE input voltage low  | VCEL    |                       | 0    | -    | 0.6  | V    |  |  |
| CE input current  | ICE     | VCE=12V               | -    | -    | 40   | μΑ   |  |  |
| Over voltage protect voltage  | Vovp    |                       | 10.2 | 11.0 | 11.8 | V    |  |  |
| FB over voltage protect   | VFBovp  |                       | 110  | 120  | 130  | %    |  |  |
| Rop pin current   | Irop    | Io=5mA, Vrop=1.47V    | 153  | 170  | 187  | μΑ   |  |  |
| Rop threshold voltage   | Vth_op  | Rop=H→L               | 1.40 | 1.47 | 1.54 | V    |  |  |
| Rop hysteresis voltage  | Vhys_op |                       | 0.02 | 0.03 | 0.04 | V    |  |  |
| Rsc pin current   | Irsc    | Io=100mA, Vrsc=1.47V  | 216  | 240  | 264  | μA   |  |  |
| Rsc threshold voltage   | Vth_sc  | Rsc=L→H               | 1.40 | 1.47 | 1.54 | V    |  |  |
| Rsc hysteresis voltage  | Vhys_sc |                       | 0.02 | 0.03 | 0.04 | V    |  |  |
| Err_op output voltage   | Verr_op | Vrop=L, Ierr_op=0.5mA | -    | -    | 0.2  | V    |  |  |
| Err_sc output voltage   | Verr_sc | Vrsc=H, Ierr_sc=0.5mA | -    | -    | 0.2  | V    |  |  |
| CD pin current  | Icd     | Vcd=0V                | 3.0  | 5.0  | 7.0  | μΑ   |  |  |
| CD threshold voltage  | Vth_cd  | Vcd=L→H               | 1.40 | 1.47 | 1.54 | V    |  |  |

### **Test Circuit**



### **Application Circuit**

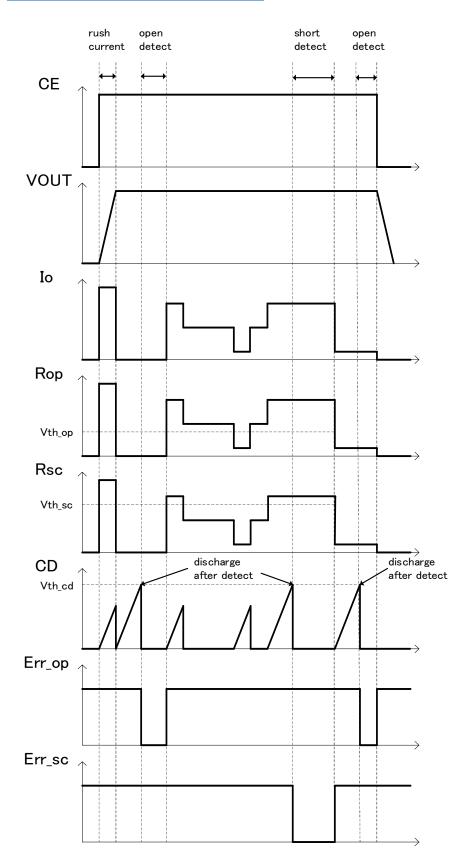


(Reference example of external parts)

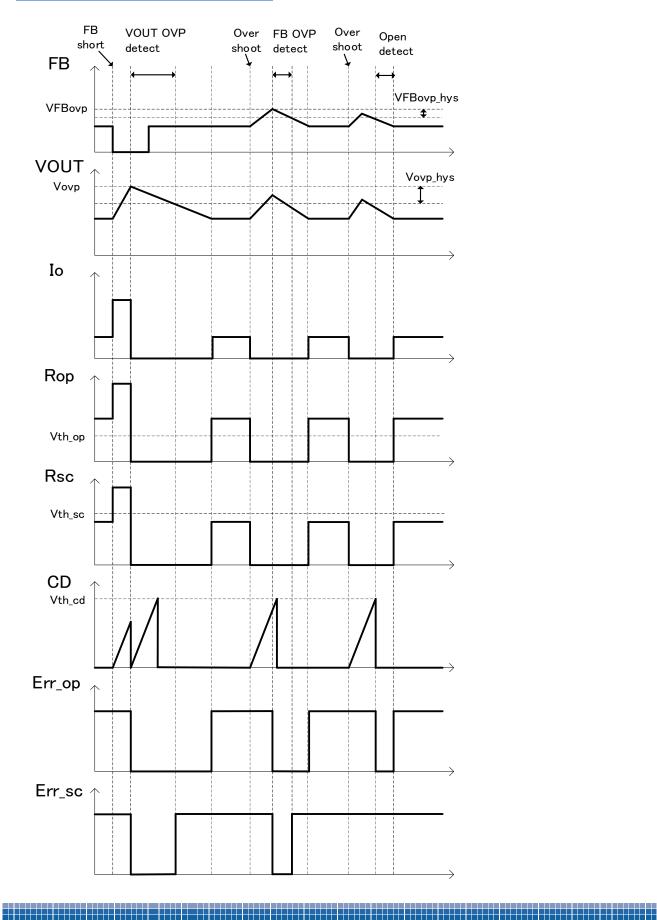
- Output capacitor Co
   Ceramic capacitor 4.7µF rated over 50V
- Input capacitor Cin
   Ceramic capacitor 4.7µF rated over 50V
- Adjustable resistance R2  $10k\Omega \sim 100k\Omega$

- Phase compensation Cfb
- Ceramic capacitor 1000pF rated over 50V
- In the event a problem which may affect industrial property or any other rights of us or a third party is encountered during the use of information described in these circuit, we shall not be liable for any such problem, nor grant a license therefore.

### Timing Chart (Open, short detection)



### Timing Chart (FB OVP,OVP)



### Feature description

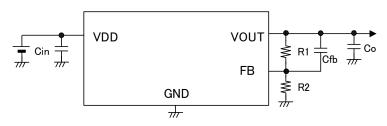
Detection delay time setting will be common for open load/short-circuit detection .
 So the short-circuit detection delay time and the open load delay time become same.

2. Each terminal output when detecting it abnormally, will be the following table.

| Terminal   | Detection |         |         |               |          |          |          |  |  |  |
|------------|-----------|---------|---------|---------------|----------|----------|----------|--|--|--|
|            | Normal    | Open    | Short   | Current Limit | TSD      | OVP      | FB OVP   |  |  |  |
| Err_op     | High      | Low     | High    | High          | Low      | Low      | Low      |  |  |  |
| Err_sc     | High      | High    | Low     | Low           | Low      | Low      | Low      |  |  |  |
| LDO output | Enabled   | Enabled | Enabled | Disabled      | Disabled | Disabled | Disabled |  |  |  |

3. Output voltage can be set with external resistor. Output voltage range is  $5V \sim 10V$ . Use resistance value in the range of below formula.

VOUT=VFB×(R1+R2) $\div$ R2 VFB=2.350V 5V $\leq$ VOUT $\leq$ 10V 10k $\Omega \leq$ R2 $\leq$ 100k $\Omega$ 



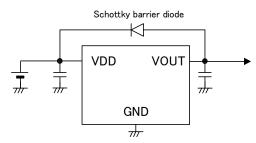
4. The set value can be designed the following calculation for Open detect resistance and short detect resistance, delay capacitance.

Rop=Vth\_op÷Irop Rsc=Vth\_sc÷Irsc Cd=(td×Icd)÷Vth\_cd

Rop:Open detect resistance Rsc:Short detect resistance Cd:Delay capacitance Vth\_op:Rop threshold voltage Vth\_sc:Rsc threshold voltage Vth\_cd:Cd threshold voltage Irop:Rop pin current Irsc:Rsc pin current Icd:CD pin current td:Detect delay time

#### Note

- 1. Please use this IC within the stated absolute maximum ratings. The IC is liable to malfunction if the ratings be exceeded.
- There is a possibility that it becomes impossible to maintain this performance and reliability IC original if use it exceeding recommended operation voltage.
   Please use it in recommended operation voltage.
- 3. Due to restrictions on the package power dissipation, the output current value may not be satisfied. Attention should be paid to the power dissipation of the package when the output current is large or the voltage between Input and Output is high.
- 4. The output capacitor is required between output and GND to prevent oscillation.
- 5. The ESR of capacitor must be defined in ESR stability area. It is possible to use a ceramic capacitor without ESR resistance for output.
- 6. The capacitor has dependency by the supply voltage and temperature. It is able to unstable operation when you use the capacitor with intense capacitance change such as micro. Please use effective capacitance of over  $4.0\mu$ F and temperature characteristic of over X7R.
- 7. The wire of VDD and GND is required to print full ground plane for noise and stability.
- 8. The input capacitor to be by pass capacitor, must be connected a distance of less than 1cm from input pin.
- 9. In case the output voltage is above the input voltage, the overcurrent flow by internal parasitic diode from output to input. In such application, the external bypass diode must be connected between output and input pin.



- 10. The FB terminal is affected by the noise. Please be careful about pattern enough. It is able to operate unstable in the influence of floating capacity.
- 11. The over current protection circuit built in this IC is vertical type.
- 12. It is possible to become unstable operation when using it with Dropout voltage no margin. Please evaluate it enough when there is no margin in Dropout voltage.
- It is possible to increase output voltage if the condition is low output current(under 1mA) and high temperature. The provision is to add load(over 1mA).

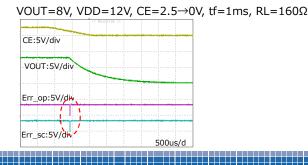
#### Note

- 14. If negative voltage over maximum rating for VOUT, Connected schottky barrier diode between VOUT-GND, and the voltage is in within rating.
- 15. It is possible to unstable when this IC is used in high electromagnetic field. Please evaluate IC on the set.
- 16. It is a possible that IC generates heat when the output terminal is short-circuited.
  The thermal shutdown circuit operates in this situation, and it will do operation that protects IC.
  However the thermal shutdown circuit is designed only to prevent thermal runaway,
  Do not continue to use that the operation of this circuit is assumed.
  The characteristic changes in the substrate condition.
  Please evaluate IC in the set.
- 17. When establishing an open load detection current, please consider a release hysteresis.
- When LDO start up, inrush current occurs.
   When start up, it is possible that inrush current instead of short-circuit current is detected.
   Please be sure to establish the detection delay time by adjusting Cd capacitor not to detect short-circuit until LDO starts.
- 19. If the voltage between input and output is less than 1.5V, Rop & Rsc current fluctuates. Please use the input voltage under the condition of output voltage +1.5V or more.
- 20. Rop and Rsc pin is high impedance to out current, So the chattering occur to influence of noise. If chattering occur, adding capacitance reduce the noise.
- When output voltage and current change transiently, Err\_op or Err\_sc may be release detection. Because no delay time for Open and short release detection. Detect again after detection delay time.

VOUT=8V, VDD=16V $\Leftrightarrow$ 10V, tr=tf=1V/us, RL=80 $\Omega$ (short detect:100mA)

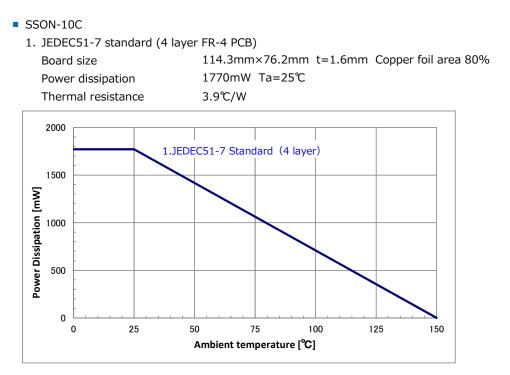
| VDD:10V/div   |                              |   |               |    |
|---------------|------------------------------|---|---------------|----|
| VOUT:20mV/div | ndato, patro atr             | an an the state of t | واختلامهم     |    |
| Err_op:5V/div | and be dealed and the second |   | ina nde el te |    |
| Err_sc:5V/div |                              |   |               |    |
| 1 N. /        | <u>\</u> /                   |   | 50ms/c        | łi |

22. It is possible that Err\_op and Err\_sc voltage output L voltage once when turn off. If this is problem, please set that it will not be detected by microcomputer.



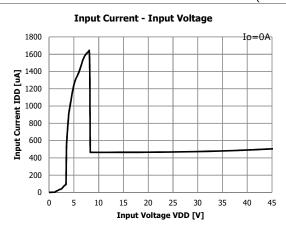
### **About Power dissipation**

The Power dissipation change if board to mount IC change because radiative heat fix at board. It is reference data below, Evaluate IC in the set.

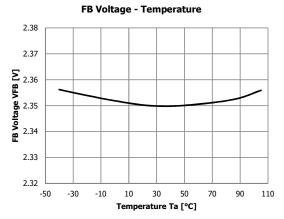


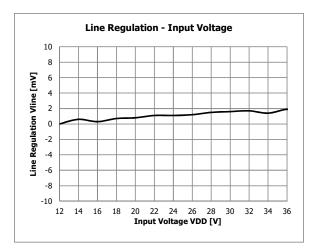
It is recommended to layout the VIA for heat radiation in the GND pattern of reverse (of IC) when there is the GND pattern in the inner layer (in using multiplayer substrate). By increasing these copper foil pattern area of PCB, Power dissipation improves.

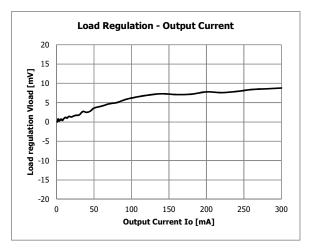
### **Typical Performance Characteristics**

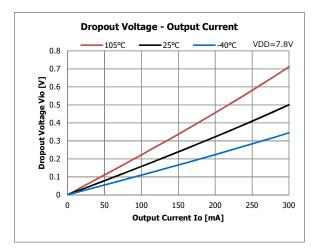


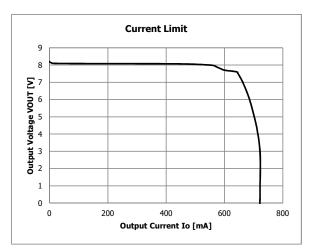
(VDD=12V, VCE=2.5V, Io=1mA, Ta=25℃, unless otherwise specified)



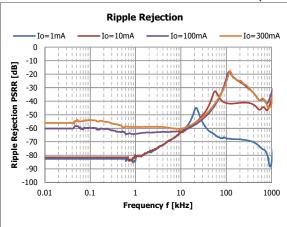




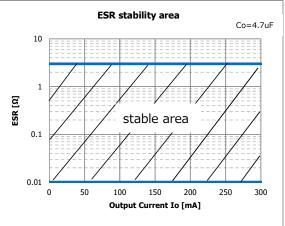


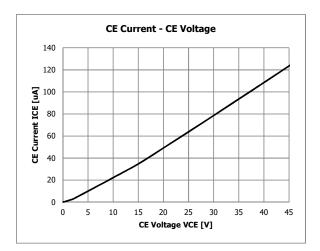


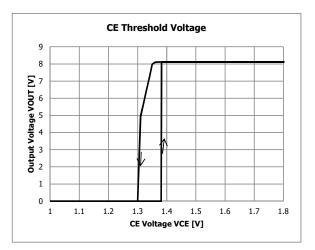
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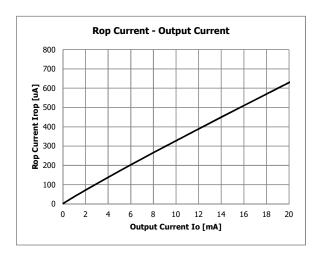


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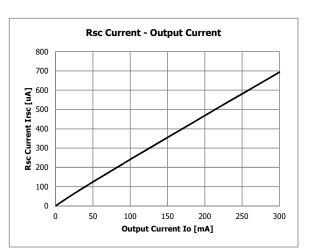




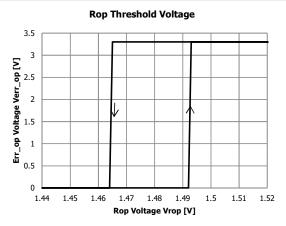


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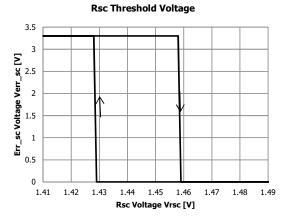
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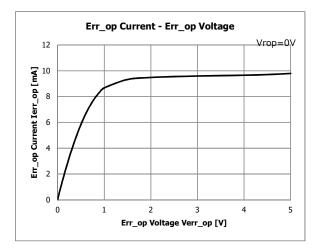


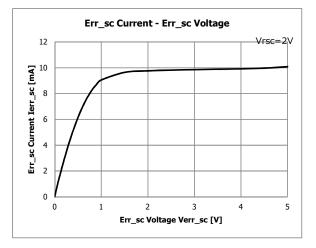
### Typical Performance Characteristics

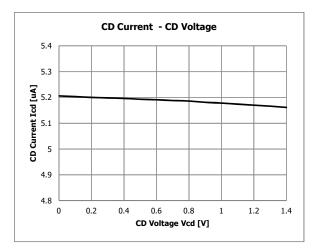


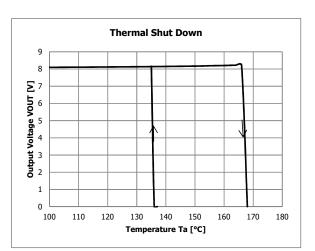
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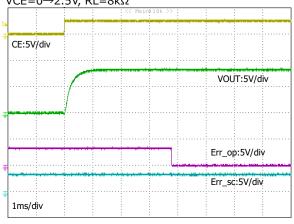


### Typical Performance Characteristics

Turn On Transient Response

Open Detect(Io=1mA)

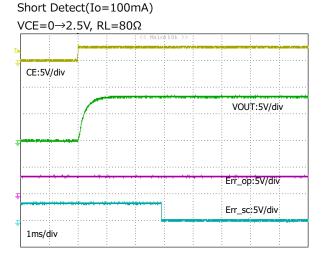
VCE=0→2.5V, RL=8kΩ



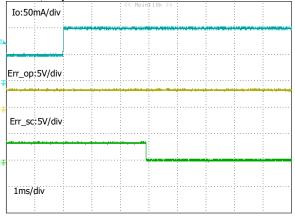
 Load Transient Response (Err\_op, Err\_sc) Open Detect(Io=50mA→1mA)

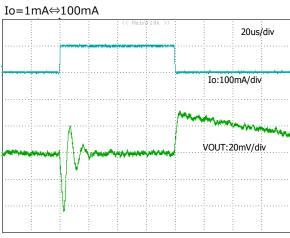
|               | : << Mai | n≇10k >> :                          |                    | - |      |
|---------------|----------|-------------------------------------|--------------------|---|------|
| Io:50mA/div   |          |                                     |                    |   |      |
|               |          | 1                                   |                    |   |      |
|               |          |                                     | <br>               | : |      |
| 1             |          |                                     |                    |   |      |
|               |          |                                     |                    | - |      |
|               |          |                                     | <br>and the second |   |      |
|               |          |                                     |                    |   |      |
|               |          |                                     |                    |   |      |
| Err_op:5V/div |          |                                     | <br>               |   |      |
| <u></u>       |          | 🛶                                   |                    |   |      |
|               |          | 1                                   |                    |   |      |
|               |          | . : السور وي الم                    | <br>               |   |      |
|               |          |                                     |                    |   | 6.00 |
| Err_sc:5V/div |          |                                     |                    |   |      |
| EII_SC:SV/UIV |          |                                     |                    |   |      |
|               |          |                                     |                    | : |      |
|               |          |                                     |                    |   |      |
|               |          |                                     |                    |   |      |
|               |          |                                     | <br>               |   |      |
|               |          |                                     |                    |   |      |
|               |          |                                     |                    |   |      |
|               |          | • • • • • • • • • • • • • • • • • • | <br>               |   |      |
| 1ms/div       |          |                                     |                    |   |      |
|               |          |                                     |                    | - |      |
|               | :        | : :                                 |                    | : | :    |

(VDD=12V, VCE=2.5V, Io=1mA, Ta=25°C, unless otherwise specified)



#### Short Detect(Io=50mA→100mA)





### Io=1mA⇔300mA



## Load Transient Response (VOUT)

## Disclaimers (Handling Precautions)

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- 2. The circuit examples and the usages described herein are for reference only, and do not guarantee the success of any specific mass-production design.

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The entire system in which the products are used must be sufficiently evaluated and judged whether the products are allowed to apply for the system on customer's own responsibility.

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